

TCAN1472-Q1 Automotive Fault-Protected CAN FD Transceiver with Signal Improvement Capability (SIC) and Standby Mode

1 Features

- AEC Q100 (Grade 1): Qualified for automotive applications
- **Functional Safety-Capable**
 - Documentation available to aid functional safety system design
- Meets the requirements of ISO 11898-2:2024 standard including CAN SIC specifications of Annex A
- Classical CAN and CAN FD up to 8Mbps
 - Actively improves the bus signal by reducing ringing effects in complex topologies
 - Backward compatible for use in classic CAN networks
- V_{IO} level shifting supports: 1.7V to 5.5V
- **Operating Modes**
 - Normal mode
 - Low-power standby mode supporting remote wake-up request
- Passive behavior when unpowered
 - Bus and logic terminals are high impedance (no load to operating bus or application)
 - Hot plug capable: power up or down glitch free operation on bus and RXD output
 - Defined device behavior with floating logic pins and in undervoltage supply conditions
- Protection features
 - IEC ESD protection on bus pins
 - ±58V CAN bus fault tolerant
 - Undervoltage protection on V_{CC} and V_{IO} (V variants only) supply terminals
 - TXD dominant state timeout (TXD DTO) Thermal shutdown protection (TSD)
- Available in SOIC (8), small footprint SOT-23 (8) and leadless, VSON (8) package with wettable flanks for improved automated optical inspection (AOI) capability

2 Applications

- Automotive gateway
- Advanced driver assistance system (ADAS)
- Body electronics and lighting ٠
- Hybrid, electric & powertrain systems
- Automotive infotainment & cluster

3 Description

The TCAN1472-Q1 devices are high speed Controller Area Network (CAN) SIC transceiver that meet the physical layer requirements of the ISO 11898-2:2024 Annex A Signal Improvement Capability (SIC) specifications. The devices reduce signal ringing at dominant-to-recessive edge and enable higher throughput in complex network topologies. Signal improvement capability allows the applications to extract real benefit of CAN FD (flexible data rate) by operating at 2Mbps, 5Mbps or higher in large networks with multiple unterminated stubs.

The devices meet the timing specifications mandated by ISO 11898-2:2024 Annex A SIC specifications, and thus have much tighter bit timing symmetry compared to a regular CAN FD transceivers. This provides a larger timing window to sample the correct bit, and enables error-free communication in large complex star networks where ringing and bit distortion are inherent.

These devices are pin-compatible to 8-pin CAN FD transceivers, such as TCAN1044A-Q1 or TCAN1042-Q1.

The TCAN1472-Q1 devices with suffix 'V' include internal logic level translation via the VIO logic supply terminal to allow for interfacing directly to 1.8V, 2.5V, or 3.3V controllers. The transceivers support low power standby mode which allows remote wakeup via CAN bus compliant with ISO 11898-2:2024 defined wake-up pattern (WUP). The device family also includes many protection features such as undervoltage detection, thermal shutdown (TSD), driver dominant timeout (TXD DTO), and ±58V bus fault protection.

Package Information

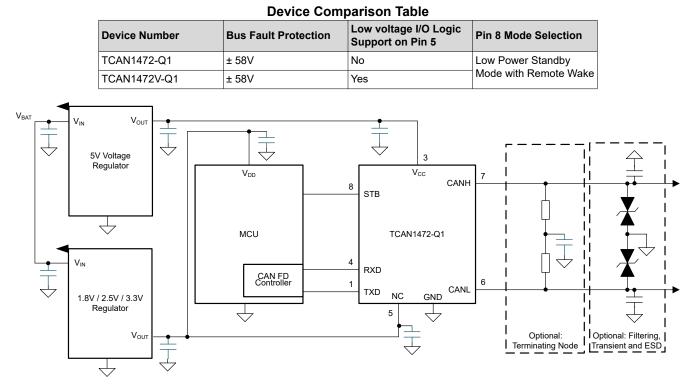
PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
	SOT-23 (DDF)	2.9mm x 2.8mm
TCAN1472-Q1	VSON (DRB)	3mm x 3mm
	SOIC (D)	4.9mm x 6mm

(1) For more information, see Section 11.

The package size (length × width) is a nominal value and (2) includes pins, where applicable.







Simplified Block Diagram



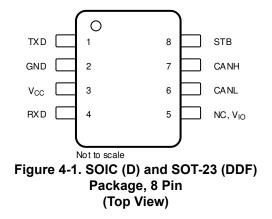
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4 Pin Configurations and Functions



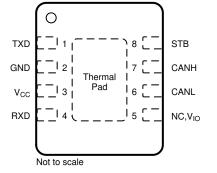


Figure 4-2. VSON (DRB) Package, 8 Pin (Top View)

Table 4-1. Pin Functions

PINS		ТҮРЕ	DESCRIPTION	
NAME	NO.	ITFE	DESCRIPTION	
TXD	1	Digital Input	CAN transmit data input, integrated pull-up	
GND	2	GND	Ground connection	
V _{CC}	3	Supply	5V supply voltage	
RXD	4	Digital Output	CAN receive data output, tristate when powered off	
V _{IO}	5	Supply	Logic supply voltage	
NC	- ⁵		No Connect (not internally connected); Devices without V _{IO}	
CANL	6	Bus IO	Low-level CAN bus input/output line	
CANH	7	Bus IO	High-level CAN bus input/output line	
STB	8	Digital Input	Standby mode control input, integrated pull-up	
Thermal Pad (VSON only)		_	Electrically connected to GND, connect the thermal pad to the printed circuit board (PCB) ground plane for thermal relief	



5 Specifications

5.1 Absolute Maximum Ratings

(1) (2)

		MIN	МАХ	UNIT
V _{CC}	Supply voltage	-0.3	6	V
V _{IO}	Supply voltage I/O level shifter (Devices with the "V" suffix)	-0.3	6	V
V _{BUS}	CAN bus I/O voltage range on CANH and CANL	-58	58	V
V _{DIFF}	Max differential voltage between CANH and CANL V_{DIFF} = (CANH - CANL)	-45	45	V
V _{Logic_Input}	Logic pin input voltage (TXD, STB)	-0.3	6	V
V _{RXD}	Logic output voltage range (RXD)	-0.3	6	V
I _{O(RXD)}	RXD output current	-8	8	mA
TJ	Junction temperature	-40	165	°C
T _{STG}	Storage temperature	-65	150	°C

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) All voltage values, except differential I/O bus voltages, are with respect to ground terminal.

5.2 ESD Ratings

				VALUE	UNIT
		A	All pins	±4000	V
V _{ESD}	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	CANH and CANL with respect to GND	±10000	V
		Charged-device model (CDM), per AEC Q100-011 for all pins		±750	V

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

5.3 ESD Ratings, IEC Transients

				VALUE	UNIT
			SAE J2962-2 per ISO 10605 Powered contact discharge	±8000	V
V _{ESD}	System level electrostatic discharge		SAE J2962-2 per ISO 10605 Powered air discharge		V
		-	IEC 62228-3 per ISO 10605	±8000	V
			Pulse 1	-100	V
	ISO 7627 2 Transient immunitu(1)		Pulse 2a	±8000 ±15000 ±8000 -100 75 -150 100	V
VTrop	130 7037-2 Transient inimunity		Pulse 3a	-150	V
V _{Tran} ISO 7637-2 Transient immunity ⁽¹⁾ CAN bus terminals (CANH, CANL) to GND Pulse 1 Pulse 2a Pulse 3a Pulse 3b	Pulse 3b	100	V		
	Direct capacitor coupling, SAE J2962-2 per ISO 7637-3 ⁽²⁾	-	DCC slow transient pulse	±30	V

Tested according to IEC 62228-3:2019 CAN Transceivers, Section 6.3; standard pulses parameters defined in ISO 7637-2 (2011)
 Tested according to SAE J2962-2

5.4 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	4.5	5	5.5	V
V _{IO}	Supply voltage for I/O level shifter (Devices with V_{IO})	1.7		5.5	V
I _{OH(RXD)}	RXD terminal high-level output current	-1.5			mA
I _{OL(RXD)}	RXD terminal low-level output current			1.5	mA
Tj	Junction temperature	-40		150	°C

5.5 Thermal Characteristics

THERMAL METRIC ⁽¹⁾		TCAN1472(V)-Q1			
		D (SOIC)	DDF (SOT)	DRB (VSON)	UNIT
R _{OJA}	Junction-to-ambient thermal resistance	113.6	129.2	52.3	°C/W
R _{OJC(top)}	Junction-to-case (top) thermal resistance	52.5	55.0	58.4	°C/W
R _{OJB}	Junction-to-board thermal resistance	61.1	48.1	24.7	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	7.4	1.7	1.7	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	60.2	47.9	24.6	°C/W
R _{OJC(bot)}	Junction-to-case (bottom) thermal resistance	-	-	8.9	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.6 Supply Characteristics

parameters valid over recommended operating conditions with -40°C $\leq T_J \leq 150$ °C (Typical values are at V_{CC} = 5 V, V_{IO} = 3.3 V (for devices with V_{IO}), Device ambient maintained at 27°C) unless otherwise noted

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
		Dominant	$\label{eq:transform} \begin{array}{l} TXD = 0 \ V, \ STB = 0 \ V \\ R_L = 60 \ \Omega, \ C_L = \text{open} \\ See \ Figure \ 6-1 \end{array}$		50	70	mA
	Supply current normal	Dominant	TXD = 0 V, STB = 0 V R _L = 50 Ω, C _L = open See Figure 6-1		55	80	mA
	mode	Recessive	$TXD = V_{IO}, STB = 0 V$ R _L = 50 Ω, C _L = open See Figure 6-1		7	11	mA
		Dominant with bus fault	TXD = 0 V, STB = 0 V CANH = CANL = ±25 V R _L = open, C _L = open See Figure 6-1			130	mA
I _{CC}			TXD = STB = V_{IO} , R_L = 50 Ω , C_L = open, Tj <= 85 °C, See Figure 6-1			1	
	Supply current standby $m = V_{IO}$)	ode (devices with	$\label{eq:transformation} \begin{split} TXD &= STB = V_{IO} \text{ , } R_{L} = 50 \ \Omega \text{, } C_{L} = open, \\ Tj &<= 125 \ ^\circC \text{, } See Figure 6-1 \end{split}$		0.2	2	μA
			$\label{eq:transformation} \begin{split} TXD &= STB = V_{IO} \text{ , } R_L = 50 \ \Omega \text{, } C_L = open, \\ Tj <= 150 \ ^\circC \text{, See Figure 6-1} \end{split}$			5	
			TXD = STB = V_{CC} , R_L = 50 Ω , C_L = open, Tj <= 85 °C, See Figure 6-1			15	
	Supply current standby m V_{IO})	ode (devices without	$\label{eq:transformation} \begin{array}{l} TXD=STB=V_{CC} \text{ , } R_{L}=50 \ \Omega \text{, } C_{L}=open, \\ Tj <= 125 \ ^{\circ}C, \ See \ Figure \ 6-1 \end{array}$			16	μA
			TXD = STB = V_{CC} , R_L = 50 Ω , C_L = open, Tj <= 150 °C, See Figure 6-1			21	μΑ



5.6 Supply Characteristics (continued)

parameters valid over recommended operating conditions with -40°C $\leq T_J \leq 150$ °C (Typical values are at V_{CC} = 5 V, V_{IO} = 3.3 V (for devices with V_{IO}), Device ambient maintained at 27°C) unless otherwise noted

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{IO} Devices with V_{IO}	I/O supply current normal	Dominant	TXD = 0 V, STB = 0 V $R_L = 60 \Omega$, $C_L = open$ RXD floating		125	300	μA
	mode	Recessive	$\begin{split} \text{TXD} &= \text{V}_{\text{IO}}, \text{STB} = 0 \text{V} \\ \text{R}_{\text{L}} &= 60 \Omega, \text{C}_{\text{L}} = \text{open} \\ \text{RXD floating} \end{split}$		25	48	μA
	I/O supply current standby mode		$ \begin{array}{l} \text{TXD} = \text{V}_{\text{IO}}, \text{STB} = \text{V}_{\text{IO}} \\ \text{R}_{\text{L}} = 60 \; \Omega, \; \text{C}_{\text{L}} = \text{open} \\ \text{RXD floating}, \; \text{Tj} <= 85 \; ^{\circ}\text{C} \\ \end{array} $			13.5	
			$ \begin{array}{l} \text{TXD} = \text{V}_{\text{IO}}, \text{STB} = \text{V}_{\text{IO}} \\ \text{R}_{\text{L}} = 60 \; \Omega, \; \text{C}_{\text{L}} = \text{open} \\ \text{RXD floating}, \; \text{Tj} <= 125 \; ^{\circ}\text{C} \\ \end{array} $		8.5	15	μA
			$\begin{array}{l} \text{TXD} = \text{V}_{\text{IO}}, \text{STB} = \text{V}_{\text{IO}} \\ \text{R}_{\text{L}} = 60 \Omega, \text{C}_{\text{L}} = \text{open} \\ \text{RXD floating, Tj} <= 150 ^{\circ}\text{C} \end{array}$			16	
UV _{CC(R)}	Undervoltage detection V _{CC}	; rising	Ramp up		4.2	4.4	V
UV _{CC(F)}	Undervoltage detection on V _{CC} falling		Ramp down	3.5	4		V
UV _{IO(R)}	Undervoltage detection V_{IO} rising (Devices with $V_{IO})$		Ramp up		1.6	1.65	V
UV _{IO(F)}	Undervoltage detection on V with V_{IO})	V _{IO} falling (Devices	Ramp down	1.4	1.5		V

5.7 Dissipation Ratings

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
P _D	Average power dissipation	V_{CC} = 5 V, V_{IO} = 3.3 V, T_{J} = 27°C, R_{L} = 60Ω, C_{L_RXD} = 15 pF TXD input = 250 kHz 50% duty cycle square wave	60		mW	
	Normal mode	$\label{eq:V_CC} \begin{array}{l} V_{CC}=5.5 \text{ V}, \text{ V}_{IO}=5.5 \text{ V}, \text{ T}_{J}=150^{\circ}\text{C}, \text{ R}_{L}=50\Omega, \\ C_{L_RXD}=15 \text{ pF} \\ \text{TXD input}=2.5 \text{ MHz } 50\% \text{ duty cycle square} \\ \text{wave} \end{array}$		120		mW
T _{TSD}	Thermal shutdown temperature			192		°C
T _{TSD_HYS}	Thermal shutdown hysteresis		10		U	

5.8 Electrical Characteristics

parameters valid over recommended operating conditions with -40°C $\leq T_J \leq 150$ °C (Typical values are at V_{CC} = 5 V, V_{IO} = 3.3 V, Device ambient maintained at 27°C) unless otherwise noted

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Driver Elec	trical Characteristics						
V _{CANH(D)}		CANH	V _{CC} = 4.75 V to 5.25 V, TXD = 0 V, STB =	3	3.5	4.26	V
V _{CANL(D)}	Dominant output voltage normal mode	CANL	−0 V 45 Ω ≤ R _L ≤ 65 Ω, C _L = open, See Figure 6-2 and Figure 7-5	0.75	1.5	2.01	V
V _{CANH(D)}	_	CANH	V _{CC} = 4.5 V to 5.5 V, TXD = 0 V, STB = 0	2.75	3.5	4.5	V
V _{CANL(D)}	Dominant output voltage normal mode	CANL	V 50 Ω ≤ R _L ≤ 65 Ω, C _L = open, See Figure 6-2 and Figure 7-5	0.5	1.5	2.25	V
V _{CANH(R)} , V _{CANL(R)}	Recessive output voltage normal mode	CANH and CANL	$ \begin{array}{l} V_{CC} = 4.75 \; V \; \text{to} \; 5.25 \; V, \; TXD = V_{\text{IO}}, \; STB = \\ 0 \; V \\ 45 \; \Omega \leq R_{L} \leq 65 \; \Omega \;, \; C_{L} = open \; See \; Figure \\ \textbf{6-2} \; and \; Figure \; \textbf{7-5} \end{array} $	2.256		2.756	V
V _{CANH(R)} , V _{CANL(R)}	Recessive output voltage normal mode	CANH and CANL	$\label{eq:VCC} \begin{array}{l} V_{CC} = 4.5 \mbox{ V to } 5.5 \mbox{ V, TXD} = V_{IO}, \mbox{ STB} = 0 \\ V \\ R_L = \mbox{open} \mbox{ (no load)}, C_L = \mbox{open}, \\ \mbox{ See Figure 6-2 and Figure 7-5 } \end{array}$	2	2.5	3	V

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5.8 Electrical Characteristics (continued)

parameters valid over recommended operating conditions with -40°C $\leq T_J \leq 150$ °C (Typical values are at V_{CC} = 5 V, V_{IO} = 3.3 V, Device ambient maintained at 27°C) unless otherwise noted

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
M	M 43 09		$ \begin{array}{l} V_{CC} = 4.75 \; V \; to \; 5.25 \; V, \; TXD = 250 \; kHz, \; 1 \\ MHz, \; 2.5 \; MHz, \; STB = 0 \; V \\ 45 \; \Omega \leq R_L \leq 65 \; \Omega, \; C_{SPLIT} = 4.7 \; nF, \; C_L = \\ open, \\ See \; Figure \; 6-2 \; and \; Figure \; 8-2 \\ \end{array} $	0.95		1.05	V/V
V _{SYM}	(V _{O(CANH)} + V _{O(CANL)})/(V _{CAN}	_{I(R)} + V _{CANL(R)})	$\label{eq:V_CC} \begin{array}{l} V_{CC} = 4.5 \ V \ to \ 5.5 \ V, \ TXD = 250 \ kHz, \ 1 \\ MHz, \ 2.5 \ MHz, \ STB = 0 \ V \\ 45 \ \Omega \leq R_L \leq 65 \ \Omega, \ C_{SPLIT} = 4.7 \ nF, \ C_L = \\ open, \\ See \ Figure \ 6-2 \ and \ Figure \ 8-2 \end{array}$	0.9		1.1	V/V
			$\begin{array}{l} V_{CC} = 4.75 \ V \ to \ 5.25 \ V, \ TXD = 0 \ V, \ STB = \\ 0 \ V \\ 45 \ \Omega \leq R_L \leq 65 \ \Omega, \ C_L = \ open, \\ See \ Figure \ 6-2 \ and \ Figure \ 7-5 \end{array}$	1.5		3	V
			$ \begin{array}{l} V_{CC} = 4.75 \ V \ to \ 5.25 \ V, \ TXD = 0 \ V, \ STB = \\ 0 \ V \\ 45 \ \Omega \leq R_L \leq 70 \ \Omega, \ C_L = open, \\ See \ Figure \ 6-2 \ and \ Figure \ 7-5 \end{array} $	1.5		3.3	V
V _{DIFF(D)}	Differential output voltage normal mode Dominant	CANH - CANL	$\label{eq:V_CC} \begin{array}{l} V_{CC} = 4.5 \mbox{ V to } 5.5 \mbox{ V, TXD} = 0 \mbox{ V, STB} = 0 \\ V \\ 50 \Omega \leq R_L \leq 65 \Omega, C_L = \mbox{ open,} \\ \mbox{ See Figure 6-2 and Figure 7-5 } \end{array}$	1.5		3	V
			$\label{eq:V_CC} \begin{array}{l} V_{CC} = 4.5 \mbox{ V to } 5.5 \mbox{ V, TXD} = 0 \mbox{ V, STB} = 0 \\ V \\ 45 \Omega \leq R_L \leq 70 \Omega, C_L = \mbox{ open,} \\ \mbox{ See Figure 6-2 and Figure 7-5 } \end{array}$	1.4		3.3	V
		$\label{eq:transformation} \begin{split} TXD &= 0 \ V, \ STB &= 0 \ V \\ R_L &= 2240 \ \Omega, \ C_L &= \text{open}, \\ See \ Figure \ 6-2 \ and \ Figure \ 7-5 \end{split}$	1.5		5	V	
V.	Differential output voltage normal mode Dominant	CANH - CANL	$\begin{array}{l} TXD=V_{ O},STB=0\;V\\ 45\;\Omega\leqR_{L}\leq65\;\Omega,C_{L}=open,\\ See\;Figure\;6-2\;and\;Figure\;7-5 \end{array}$	-50		50	mV
V _{DIFF(R)}	Differential output voltage normal mode Dominant	CANH - CANL	$\label{eq:transformation} \begin{split} \text{TXD} &= \text{V}_{\text{IO}}, \text{STB} = 0 \text{V} \\ \text{R}_{\text{L}} &= \text{open}, \text{C}_{\text{L}} = \text{open}, \\ \text{See Figure 6-2 and Figure 7-5} \end{split}$	-50		50	mV
V _{CANH} (INACT)		CANH	TXD = STB = V _{IO}	-0.1		0.1	V
V _{CANL(INACT)}	Bus output voltage standby mode	CANL	R_L = open , C_L = open,	-0.1		0.1	V
V _{DIFF(INACT)}		CANH - CANL	See Figure 6-2 and Figure 7-5	-0.2		0.2	V
R _{DIFF(DOM)}	Differential input resistance i	n dominant phase	TXD= 0 V, STB = 0 V, See Figure 7-2		40		Ω
R _{SE_SIC_ACT_} REC	Single ended resistance CAN recessive phase	NH/CANL in active	$V_{CC} = 4.75 \text{ V to } 5.25 \text{ V}, 2 \text{ V} \leq V_{CANH/L} \leq V_{CC} - 2 \text{ V}$	37.5	50	66.5	Ω
R _{DIFF_ACT_RE} c	Differential input resistance i phase	n active recessive	$V_{CC} = 4.75 \text{ V to } 5.25 \text{ V}, 2 \text{ V} \leq \text{V}_{CANH/L} \leq \text{V}_{CC} - 2 \text{ V}$	75	100	133	Ω
I _{CANH(OS)}	Short-circuit bus output curre	ent, TXD is	$\label{eq:V_CANH} \begin{array}{l} \text{=} -15 \text{ V to } 40 \text{ V, CANL} = \text{open}, \\ \text{TXD} = 0 \text{ V or } V_{\text{IO}} \text{ or } 250 \text{ kHz}, 2.5 \text{ MHz} \\ \text{square wave}, \\ \text{See Figure 6-7 and Figure 7-5} \end{array}$	-115		115	mA
I _{CANL(OS)}	dominant or recessive or toggling, normal mode		$\label{eq:V_CAN_L} \begin{array}{l} V_{(CAN_L)} = -15 \ V \ \text{to} \ 40 \ V, \ CANH = open, \\ TXD = 0 \ V \ \text{or} \ V_{10} \ \text{or} \ 250 \ kHz, \ 2.5 \ MHz \\ square wave, \\ See Figure 6-7 \ and Figure 7-5 \end{array}$	-115		115	mA
Receiver Elec	ctrical Characteristics						
V _{IT}	Input threshold voltage norm	al mode	-12 V \leq V _{CM} \leq 12 V, STB= 0 V, See Figure 6-3 and Figure 7-6	500		900	mV
V _{IT(STB)}	Input threshold standby mod	e	-12 V \leq V _{CM} \leq 12 V, STB= V _{IO} , See Figure 6-3 and Figure 7-6	400		1150	mV
V _{DIFF_RX(D)}	Normal mode dominant state voltage range	e differential input	-12 V \leq V _{CM} \leq 12 V, STB= 0 V, See Figure 6-3 and Figure 7-6	0.9		9	V
V _{DIFF_RX(R)}	Normal mode recessive state voltage range	e differential input	-12 V \leq V _{CM} \leq 12 V , STB= 0 V, See Figure 6-3 and Figure 7-6	-4		0.5	V



5.8 Electrical Characteristics (continued)

parameters valid over recommended operating conditions with -40°C $\leq T_J \leq 150$ °C (Typical values are at V_{CC} = 5 V, V_{IO} = 3.3 V, Device ambient maintained at 27°C) unless otherwise noted

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{DIFF_RX(D_IN} ACT)	Standby mode dominant state differential input voltage range	STB = V_{IO} , -12 V $\leq V_{CM} \leq$ 12 V, See Figure 6-3 and Figure 7-6	1.15		9	v
V _{DIFF_RX(R_IN} ACT)	Standby mode recessive state differential input voltage range	STB = V_{IO} , -12 V $\leq V_{CM} \leq$ 12 V, See Figure 6-3 and Figure 7-6	-4		0.4	V
V _{HYS}	Hysteresis voltage for input threshold normal mode	-12 V \leq V _{CM} \leq 12 V, STB= 0 V, See Figure 6-3 and Figure 7-6		100		mV
V _{CM}	Common mode range normal and standby modes	See Figure 6-3 and Figure 7-6	-12		12	v
I _{LKG(OFF)}	Unpowered bus input leakage current	$CANH = CANL = 5 V, V_{CC} = V_{IO} = GND$			5	μA
CI	Input capacitance to ground (CANH or CANL)				20	pF
C _{ID}	Differential input capacitance across bus terminals	TXD = V _{IO}			10	pF
R _{DIFF_PAS_RE} C	Differential input resistance in passive recessive phase		40		90	kΩ
R _{SE_PAS_REC}	Single ended input resistance in passive recessive phase (CANH or CANL)	- TXD = V _{IO,} STB = 0 V -12 V ≤ V _{CM} ≤ 12 V, Delta V/Delta I	20		45	kΩ
m _R	Input resistance matching [1 – (R _{IN(CANH)} / R _{IN(CANL})] × 100 %	$V_{(CAN_H)} = V_{(CAN_L)} = 5 V$	-1		1	%
TXD Termina	I (CAN Transmit Data Input)					
V _{IH}	High-level input voltage	Devices without V _{IO}	0.7 V _{CC}			V
V _{IH}	High-level input voltage	Devices with V _{IO}	0.7 V _{IO}			V
V _{IL}	Low-level input voltage	Devices without V _{IO}			0.3 V _{CC}	V
V _{IL}	Low-level input voltage	Devices with V _{IO}			0.3 V _{IO}	V
I _{IH}	High-level input leakage current	$TXD = V_{CC} = V_{IO} = 5.5 V$	-2.5	0	1	μA
IIL	Low-level input leakage current	TXD = 0 V, V _{CC} = V _{IO} = 5.5 V	-200	-100	-20	μA
ILKG_TXD(OFF)	Unpowered leakage current	$TXD = 5.5 V, V_{CC} = V_{IO} = 0 V$	-1	0	1	μA
C _{I_TXD}	Input capacitance			6		pF
RXD Termina	I (CAN Receive Data Output)	· · · ·				
V _{OH}	High-level output voltage	Devices without V_{IO} $I_O = -1.5 \text{ mA},$ See Figure 6-3	0.8 V _{CC}			v
V _{OH}	High-level output voltage	I_O = -1.5 mA, Devices with V _{IO} See Figure 6-3	0.8 V _{IO}			v
V _{OL}	Low-level output voltage	Devices without V_{IO} I _O = 1.5 mA, See Figure 6-3			0.2 V _{CC}	v
V _{OL}	Low-level output voltage	Devices with V_{IO} I _O = 1.5 mA, Devices with V_{IO} See Figure 6-3			0.2 V _{IO}	v
I _{LKG_RXD(OFF)}	Unpowered leakage current	$RXD = 5.5 V, V_{CC} = V_{IO} = 0 V$	-1	0	1	μA
STB Termina	al (Standby Mode Input)					
V _{IH}	High-level input voltage	Devices without V _{IO}	0.7 V _{CC}			V
VIH	High-level input voltage	Devices with V _{IO}	0.7 V _{IO}			V
VIL	Low-level input voltage	Devices without VIO			0.3 V _{CC}	V
VIL	Low-level input voltage	Devices with V _{IO}			0.3 V _{IO}	V
IIH	High-level input leakage current	V _{CC} = V _{IO} = STB = 5.5 V	-2		2	μA
IIL	Low-level input leakage current	V _{CC} = V _{IO} = 5.5 V, STB = 0 V	-20		-2	μA
ILKG STB(OFF)	Unpowered leakage current	STB = 5.5V, V _{CC} = V _{IO} = 0 V	-1	0	1	μA



5.9 Switching Characteristics

parameters valid over recommended operating conditions with -40°C \leq T_J \leq 150°C (Typical values are at V_{CC} = 5 V, V_{IO} = 3.3 V, Device ambient maintained at 27°C) unless otherwise noted

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Device Switching	g Characteristics					
		$\begin{array}{l} \text{See Figure 6-4} \text{ , normal mode, } V_{\text{IO}} = 4.5 \\ \text{V to } 5.5 \text{ V, } 45 \ \Omega \leq \text{R}_{\text{L}} \leq 65 \ \Omega, \ \text{C}_{\text{L}} = 100 \\ \text{pF} \ (\leq \pm 1\%), \ \text{C}_{\text{L}(\text{RXD})} = 15 \ \text{pF} \ (\leq \pm 1\%) \end{array}$		90	145	ns
tababy and	Total loop delay, driver input (TXD) to receiver	$\begin{array}{l} \text{See Figure 6-4} \text{ , normal mode, } V_{\text{IO}} = 3 \text{ V} \\ \text{to } 3.6 \text{ V}, 45 \Omega \leq \text{R}_{\text{L}} \leq 65 \Omega, \text{C}_{\text{L}} = 100 \text{pF} \\ (\leq \pm 1\%), \text{C}_{\text{L}(\text{RXD})} = 15 \text{pF} (\leq \pm 1\%) \end{array}$		95	155	ns
^t PROP(LOOP1)	output (RXD), recessive to dominant	$\begin{array}{l} \text{See Figure 6-4} \text{ , normal mode, } V_{\text{IO}} = \\ 2.25 \text{ V to } 2.75 \text{ V, } 45 \ \Omega \leq \text{R}_{\text{L}} \leq 65 \ \Omega, \ \text{C}_{\text{L}} = \\ 100 \text{ pF} \ (\leq \pm1\%), \ \text{C}_{\text{L}(\text{RXD})} = 15 \text{ pF} \ (\leq \pm1\%) \end{array}$		110	170	ns
		$\begin{array}{l} \text{See Figure 6-4} \text{ , normal mode, } V_{\text{IO}} = \\ 1.71 \text{ V to } 1.89 \text{ V, } 45 \ \Omega \leq R_{\text{L}} \leq 65 \ \Omega, \ C_{\text{L}} = \\ 100 \text{ pF} \ (\leq \pm1\%), \ C_{\text{L}(\text{RXD})} = 15 \text{ pF} \ (\leq \pm1\%) \end{array}$		125	190	ns
		$ \begin{array}{l} \text{See Figure 6-4} \text{ , normal mode, } V_{\text{IO}} = 4.5 \\ \text{V to } 5.5 \text{ V, } 45 \ \Omega \leq \text{R}_{\text{L}} \leq 65 \ \Omega, \ \text{C}_{\text{L}} = 100 \\ \text{pF} \ (\leq \pm 1\%), \ \text{C}_{\text{L}(\text{RXD})} = 15 \ \text{pF} \ (\leq \pm 1\%) \\ \end{array} $		95	150	ns
t	Total loop delay, driver input (TXD) to receiver	$\begin{array}{l} \text{See Figure 6-4} \text{ , normal mode, } V_{\text{IO}} = 3 \text{ V} \\ \text{to } 3.6 \text{ V}, 45 \ \Omega \leq \text{R}_{\text{L}} \leq 65 \ \Omega, \ \text{C}_{\text{L}} = 100 \text{ pF} \\ (\leq \pm 1\%), \ \text{C}_{\text{L}(\text{RXD})} = 15 \text{ pF} \ (\leq \pm 1\%) \end{array}$		100	160	ns
^I PROP(LOOP2)	output (RXD), dominant to recessive	$\begin{array}{l} \text{See Figure 6-4} \text{ , normal mode, } V_{\text{IO}} = \\ \text{2.25 V to 2.75 V, } 45 \ \Omega \leq \text{R}_{\text{L}} \leq 65 \ \Omega, \ \text{C}_{\text{L}} = \\ 100 \ \text{pF} \ (\leq \pm1\%), \ \text{C}_{\text{L}(\text{RXD})} = 15 \ \text{pF} \ (\leq \pm1\%) \end{array}$		110	175	ns
		$\begin{array}{l} \text{See Figure 6-4} \text{ , normal mode, } V_{\text{IO}} = \\ 1.71 \text{ V to } 1.89 \text{ V, } 45 \ \Omega \leq R_{\text{L}} \leq 65 \ \Omega, \ C_{\text{L}} = \\ 100 \text{ pF} \ (\leq \pm1\%), \ C_{\text{L}(\text{RXD})} = 15 \text{ pF} \ (\leq \pm1\%) \end{array}$		125	190	ns
t _{MODE}	Mode change time, from normal to standby or from standby to normal	See Figure 6-5			30	μs
	Filter time for a valid wake-up pattern	See Figure 7-7	0.5		0.95	μs
twk_timeout	Bus wake-up timeout value	See Figure 7-7	0.8		6	ms
Tstartup	Time duration after V_{CC} or V_{IO} has cleared rising undervoltage threshold, and device can resume normal operation				1.5	ms
T _{filter(STB)}	Filter on STB pin to filter out any glitches		0.5	1	2	μs
Driver Switching	Characteristics					
		$ \begin{array}{l} \mbox{See Figure 6-2} \ , \mbox{STB} = 0 \ V, \ \mbox{45} \ \Omega \leq R_L \leq \\ \mbox{65} \ \Omega, \ \mbox{C}_L = 100 \ \mbox{pF} \ (\leq \pm 1\%), \ \ \mbox{V}_{IO} = 4.5 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$		35	70	ns
t (TRI)	Propagation delay time, low-to-high TXD edge to	See Figure 6-2 STB = 0 V, 45 $\Omega \le R_L \le$ 65 Ω , C_L = 100 pF ($\le \pm 1\%$), V_{IO} = 3 V to 3.6 V		40	70	ns
^I prop(TxD-busrec)	driver recessive (dominant to recessive)	See Figure 6-2 STB = 0 V, 45 $\Omega \le R_L \le$ 65 Ω , C _L = 100 pF ($\le \pm 1\%$), V _{IO} = 2.25 V to 2.75 V		40	75	ns
		See Figure 6-2 STB = 0 V, 45 $\Omega \le R_L \le$ 65 Ω , C _L = 100 pF ($\le \pm$ 1%), V _{IO} = 1.71 V to 1.89 V		42	80	ns
t _{prop} (TxD-busdom)		$ \begin{array}{l} \mbox{See Figure 6-2} & , \mbox{STB} = 0 \ \mbox{V}, \mbox{45} \ \mbox{\Omega} \le \mbox{R}_L \le \\ \mbox{65} \ \mbox{\Omega}, \ \mbox{C}_L = 100 \ \mbox{pF} \ (\le \pm 1\%), \ \mbox{V}_{IO} = 4.5 \ \mbox{V} \\ \mbox{to } 5.5 \ \mbox{V} \end{array} $		35	75	ns
	Propagation delay time, high-to-low TXD edge to	See Figure 6-2 STB = 0 V, 45 $\Omega \le R_L \le$ 65 Ω , C _L = 100 pF ($\le \pm 1\%$), V _{IO} = 3 V to 3.6 V		35	75	ns
	driver dominant (recessive to dominant)	See Figure 6-2 STB = 0 V, 45 $\Omega \le R_L \le$ 65 Ω , C _L = 100 pF ($\le \pm$ 1%), V _{IO} = 2.25 V to 2.75 V		40	80	ns
		See Figure 6-2 STB = 0 V, 45 $\Omega \le R_L \le$ 65 Ω , C _L = 100 pF ($\le \pm 1\%$), V _{IO} = 1.71 V to 1.89 V		42	80	ns



5.9 Switching Characteristics (continued)

parameters valid over recommended operating conditions with -40°C $\leq T_J \leq 150$ °C (Typical values are at V_{CC} = 5 V, V_{IO} = 3.3 V, Device ambient maintained at 27°C) unless otherwise noted

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{sk(p)}	Pulse skew (t _{prop(TxD-busrec)} - t _{prop(TxD-busdom)})	$\begin{array}{l} \text{STB} = 0 \text{ V}, 45 \ \Omega \leq R_L \leq 65 \ \Omega, \ C_L = 100 \\ \text{pF} \ (\leq \pm 1\%), \ \text{See Figure 6-2} \end{array}$		1	10	ns
BUS_R	Differential output signal rise time	See Figure 6-2 , STB = 0 V, 45 $\Omega \le R_L \le 65 \ \Omega, \ C_L$ = 100 pF ($\le \pm 1\%)$		15	30	ns
t _{BUS_F}	Differential output signal fall time	See Figure 6-2 , STB = 0 V, 45 Ω \leq RL \leq 65 $\Omega,$ CL = 100 pF (\leq ±1%)		15	40	ns
t _{тхд_дто}	Dominant timeout	See Figure 6-6 , 45 Ω \leq RL \leq 65 $\Omega,$ CL = 100 pF (\leq ±1%), STB = 0 V	1.2		4.0	ms
Receiver Switchin	ng Characteristics					
		$\begin{array}{l} \text{See Figure 6-3 , STB = 0 V,} \\ \text{45 } \Omega \leq \text{R}_{\text{L}} \leq 65 \ \Omega, \ \text{C}_{\text{L}} = 100 \ \text{pF} \ (\leq \pm 1\%), \\ \text{C}_{\text{L}(\text{RXD})} = 15 \ \text{pF} \ (\leq \pm 1\%), \ \text{V}_{\text{IO}} = 4.5 \ \text{V to} \\ \text{5.5 } \ \text{V} \end{array}$		60	85	ns
t _{prop(busrec-RXD)}	Propagation delay time, bus recessive input to RXD high output (dominant to recessive)			65	95	ns
μομουσιεσιοχογ		$\begin{array}{l} \text{See Figure 6-3 STB} = 0 \text{ V}, 45 \ \Omega \leq R_L \leq \\ 65 \ \Omega, \ C_L = 100 \text{ pF} \ (\leq \pm 1\%), \ C_L(\text{RXD}) = 15 \\ \text{pF} \ (\leq \pm 1\%), \ V_{\text{IO}} = 2.25 \text{ V} \text{ to } 2.75 \text{ V} \end{array}$		70	105	ns
		$\begin{array}{l} \text{See Figure 6-3 STB} = 0 \text{ V}, 45 \ \Omega \leq R_L \leq \\ 65 \ \Omega, \ C_L = 100 \text{ pF} \ (\leq \pm 1\%), \ C_L(_{RXD}) = 15 \\ \text{pF} \ (\leq \pm 1\%), \ V_{IO} = 1.71 \text{ V to } 1.89 \text{ V} \end{array}$		80	110	ns
		$\begin{array}{l} \text{See Figure 6-3 , STB = 0 V,} \\ \text{45 } \Omega \leq \text{R}_{\text{L}} \leq 65 \ \Omega, \ \text{C}_{\text{L}} = 100 \ \text{pF} \ (\leq \pm 1\%), \\ \text{C}_{\text{L}(\text{RXD})} = 15 \ \text{pF} \ (\leq \pm 1\%), \ \text{V}_{\text{IO}} = 4.5 \ \text{V} \ \text{to} \\ \text{5.5 } \ \text{V} \end{array}$		50	75	ns
t _{prop(busdom-RXD)}	Propagation delay time, bus dominant input to RXD low output (recessive to dominant)			60	80	ns
		$\begin{array}{l} \text{See Figure 6-3 STB} = 0 \text{ V}, 45 \ \Omega \leq R_L \leq \\ 65 \ \Omega, \ C_L = 100 \text{ pF} \ (\leq \pm 1\%), \ C_{L(RXD)} = 15 \\ \text{pF} \ (\leq \pm 1\%), \ V_{IO} = 2.25 \text{ V} \text{ to } 2.75 \text{ V} \end{array}$		65	90	ns
		$ \begin{array}{l} \text{See Figure 6-3 STB = 0 V, 45 } \Omega \leq \text{R}_{\text{L}} \leq \\ \text{65 } \Omega, \ \text{C}_{\text{L}} = 100 \ \text{pF} \ (\leq \pm 1\%), \ \text{C}_{\text{L}(\text{RXD})} = 15 \\ \text{pF} \ (\leq \pm 1\%), \ \text{V}_{\text{IO}} = 1.71 \ \text{V to } 1.89 \ \text{V} \end{array} $		80	110	ns
t _{RXD_R}	RXD output signal rise time	See Figure 6-3, STB = 0 V,		8	25	ns
t _{RXD_F}	RXD output signal fall time	$C_{L(RXD)} = 15 \text{ pF}(\leq \pm 1\%)$		7	30	ns
FD Timing Charao	cteristics					
	Bit time on CAN bus output pins with $t_{BIT(TXD)} = 500$ ns	$ \begin{array}{l} \text{See Figure 6-4, V}_{CC} = 4.5 \text{ V to } 5.5 \text{ V,} \\ \text{STB} = 0 \text{ V, } 45 \ \Omega \leq \text{R}_{L} \leq 65 \ \Omega \text{ , } \text{C}_{L} = 100 \\ \text{pF, } \text{C}_{L(\text{RXD})} = 15 \text{ pF} \end{array} $	490		510	ns
t _{BIT(BUS)}	Bit time on CAN bus output pins with $t_{BIT(TXD)} = 200$ ns	$ \begin{array}{l} \text{See Figure 6-4, V}_{CC} = 4.5 \text{ V to } 5.5 \text{ V,} \\ \text{STB} = 0 \text{ V, } 45 \ \Omega \leq \text{R}_{L} \leq 65 \ \Omega \text{ , } C_{L} = 100 \\ \text{pF, } C_{L(\text{RXD})} = 15 \text{ pF} \end{array} $	190		210	ns
	Bit time on CAN bus output pins with $t_{BIT(TXD)} = 125$ ns	See Figure 6-4, V _{CC} = 4.5 V to 5.5 V, STB = 0 V, 45 $\Omega \le R_L \le 65 \Omega$, C _L = 100 pF, C _{L(RXD)} = 15 pF	115		135	ns



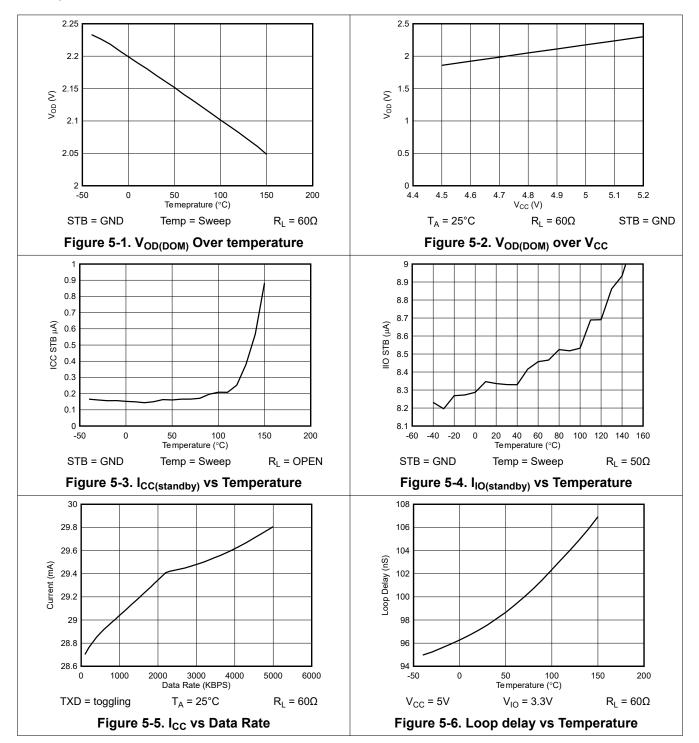
5.9 Switching Characteristics (continued)

parameters valid over recommended operating conditions with -40°C $\leq T_J \leq 150$ °C (Typical values are at V_{CC} = 5 V, V_{IO} = 3.3 V, Device ambient maintained at 27°C) unless otherwise noted

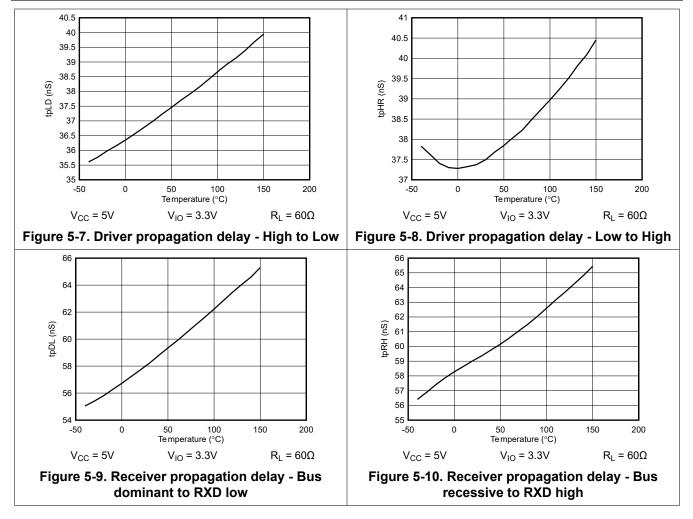
	PARAMETER	TEST CONDITIONS	MIN	TYP MAX	UNIT
		See Figure 6-4, V _{CC} = 4.75 V to 5.25 V, STB = 0 V, 45 $\Omega \le R_L \le 65 \Omega$, C _L = 100 pF, C _{L(RXD)} = 15 pF	470	520	ns
	Bit time on RXD output pins with $t_{BIT(TXD)} = 500 \text{ ns}$	$ \begin{array}{l} \mbox{See Figure 6-4, V_{CC} = 4.5 V to 5.5 V,} \\ \mbox{STB = 0 V, 45 } \Omega \leq R_L \leq 65 \ \Omega \ , \ C_L = 100 \\ \mbox{pF, } C_{L(RXD)} = 15 \ \mbox{pF} \end{array} $	470	525	ns
		$ \begin{array}{l} \mbox{See Figure 6-4, V_{CC} = 4.75 V to 5.25 V,} \\ \mbox{STB = 0 V, 45 } \Omega \leq R_L \leq 65 \ \Omega \ , \ C_L = 100 \\ \mbox{pF, } C_{L(RXD)} = 15 \ \mbox{pF} \end{array} $	170	220	ns
t _{BIT(RXD)}	Bit time on RXD output pins with t _{BIT(TXD)} = 200 ns	$ \begin{array}{l} \text{See Figure 6-4, V}_{CC} = 4.5 \text{ V to 5.5 V,} \\ \text{STB} = 0 \text{ V, } 45 \ \Omega \leq R_L \leq 65 \ \Omega \text{ , } C_L = 100 \\ \text{pF, } C_{L(\text{RXD})} = 15 \text{ pF} \end{array} $	170	225	ns
		$ \begin{array}{l} \mbox{See Figure 6-4, V_{CC} = 4.75 V to 5.25 V,} \\ \mbox{STB = 0 V, 45 } \Omega \leq R_L \leq 65 \ \Omega \ , \ C_L = 100 \\ \mbox{pF, } C_{L(RXD)} = 15 \ \mbox{pF} \end{array} $	95	145	ns
	Bit time on RXD output pins with t _{BIT(TXD)} = 125 ns	$ \begin{array}{l} \mbox{See Figure 6-4, V}_{CC} = 4.5 \ V \ to \ 5.5 \ V, \\ \mbox{STB} = 0 \ V, \ 45 \ \Omega \leq R_L \leq 65 \ \Omega \ , \ C_L = 100 \\ \mbox{pF, } C_{L(RXD)} = 15 \ \mbox{pF} \end{array} $	95	150	ns
Signal Improvem	ent Timing Characteristics				
tpas_rec_start	Start time of passive recessive phase	Time duration from TXD rising 50% edge (<5ns slope) to start of passive recessive phase	420	530	ns
t _{ACT_REC_START}	Start time of active signal improvement phase	Time duration from TXD rising 50% edge		120	ns
tACT_REC_END	End time of active signal improvement phase	(<5ns slope) to start of passive recessive phase	355		ns
	Transmitted bit width variation	V_{CC} = 4.75 V to 5.25 V, TXD <= 8Mbps, t_{Δ} Bit(Bus) = $t_{Bit(Bus)}$ - $t_{Bit(TxD)}$ STB = 0 V, 45 Ω ≤ R _L ≤ 65 Ω, C _L = 100 pF (≤ ±1%), C _{L(RXD)} = 15 pF (≤ ±1%), See Figure 6-4	-10	10	ns
t∆ Bit(Bus)		$ \begin{array}{l} V_{CC} = 4.5 \; V \; to \; 5.5 \; V, \; TXD <= 8 Mbps, \\ t_{\Delta} \; _{Bit(Bus)} = t_{Bit(Bus)} - t_{Bit(TxD)} \\ STB = 0 \; V, \; R_L = 60 \; \Omega, \; C_L = 100 \\ pF \; (\leq \pm 1\%), \; C_{L(RXD)} = 15 \; pF \; (\leq \pm 1\%), \\ See \; Figure \; 6{\text -}4 \end{array} $	-10	10	ns
	Bossived bit width veriation	$ \begin{array}{l} V_{CC} = 4.75 \; V \; \text{to} \; 5.25 \; V, \; TXD <= 8 Mbps, \\ t_{\Delta} \; BIT(RxD) = t_{Bit(RxD)} \cdot t_{Bit(TXD)} \\ STB = 0 \; V, \; 45 \; \Omega \leq R_L \leq 65 \; \Omega, \; C_L = 100 \\ pF \; (\leq \pm 1\%), \; C_{L(RXD)} = 15 \; pF \; (\leq \pm 1\%), \\ C_{L(RXD)} = 15 \; pF, \; See \; Figure \; 6\text{-}4 \end{array} $	-30	20	ns
^τ Δ BIT(RxD)	Received bit width variation	$ \begin{array}{l} V_{CC} = 4.5 \; V \; to \; 5.5 \; V, \; TXD <= 8 Mbps, \\ t_{\Delta} \; {}_{BIT(RxD)} = t_{Bit(RxD)} - t_{Bit(TxD)} \\ STB = 0 \; V, \; R_L = 60 \; \Omega, \; C_L = 100 \; pF \; (\leq \\ \pm 1\%), \; C_{L(RXD)} = 15 \; pF \; (\leq \pm 1\%), \; C_{L(RXD)} = \\ 15 \; pF, \; See \; Figure \; 6-4 \end{array} $	-30	20	ns
t _{∆ REC}	Receiver timing symmetry	$ \begin{array}{l} V_{CC} = 4.75 \; V \; to \; 5.25 \; V, \; TXD <= 8 M bps, \\ t_{\Delta} \; \text{REC} = t_{Bit(RXD)} - t_{Bit(Bus)} \\ \text{STB} = 0 \; V, \; 45 \; \Omega \leq R_L \leq 65 \; \Omega, \; C_L = 100 \\ \text{pF} \; (\leq \pm 1\%), \; C_{L(RXD)} = 15 \; \text{pF} \; (\leq \pm 1\%), \\ \text{See Figure 6-4} \end{array} $	-20	15	ns
	Receiver timing symmetry	$ \begin{array}{l} V_{CC} = 4.5 \; V \; to \; 5.5 \; V, \; TXD <= 8 Mbps, \\ t_{\Delta} \; \text{REC} = t_{Bit(RXD)} - t_{Bit(Bus)} \\ \text{STB} = 0 \; V, \; \text{R}_{L} = 60 \; \Omega, \; \text{C}_{L} = 100 \\ \text{pF} \; (\leq \pm 1\%), \; \text{C}_{L(RXD)} = 15 \; \text{pF} \; (\leq \pm 1\%), \\ \text{See Figure 6-4} \end{array} $	-20	15	ns



5.10 Typical Characteristics

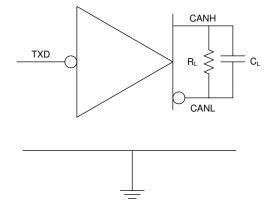








6 Parameter Measurement Information





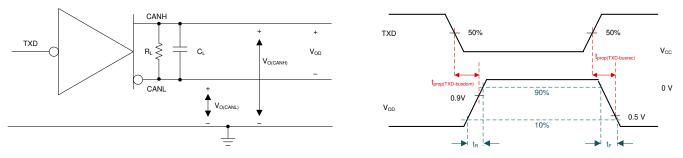


Figure 6-2. Driver Test Circuit and Measurement

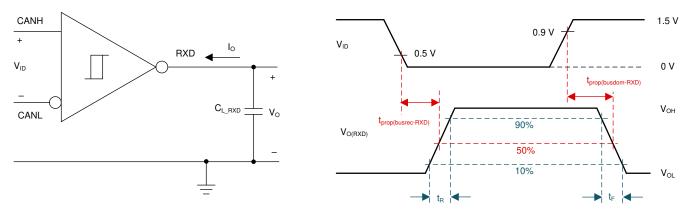
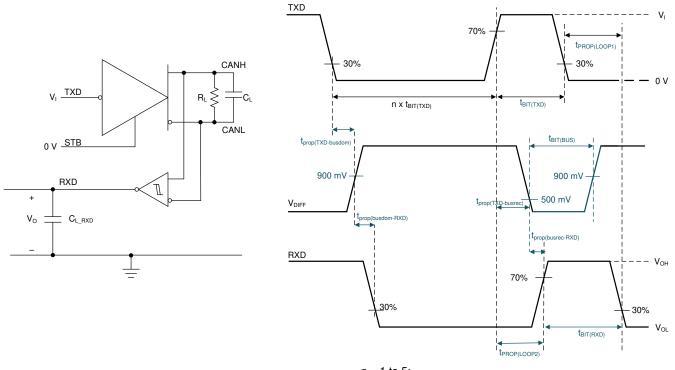


Figure 6-3. Receiver Test Circuit and Measurement

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n = 1 to 5; TXD rise/fall time < 10 ns

Figure 6-4. Transmitter and Receiver Timing Behavior Test Circuit and Measurement



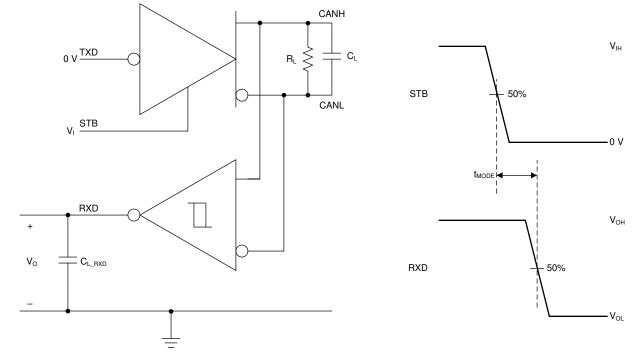


Figure 6-5. t_{MODE} Test Circuit and Measurement

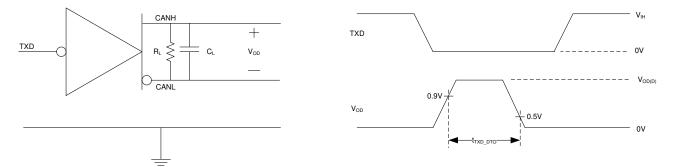
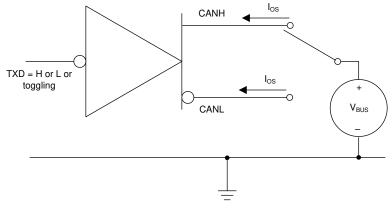


Figure 6-6. TXD Dominant Timeout Test Circuit and Measurement







7 Detailed Description

7.1 Overview

The TCAN1472-Q1 devices meet or exceed the specifications of the Annex A Signal Improvement capability (SIC) specification of ISO 11898-2:2024 Controller Area Network physical layer standard. The devices are data rate agnostic making them backward compatible for supporting classical CAN applications while also supporting CAN FD networks up to 8Mbps. These devices have standby mode support which puts the transceiver in ultra-low current consumption mode. Upon receiving a valid wake-up pattern (WUP) on the CAN bus, the device signals to the microcontroller through the RXD pin. The MCU can then put the device into normal mode using the STB pin.

The TCAN1472V-Q1 has two separate supply rails, V_{CC} bus-side supply and V_{IO} logic supply for logic-level translation for interfacing directly to 1.8V, 2.5V, 3.3V, or 5V controllers.

7.1.1 Signal Improvement

Signal improvement is an additional capability added to CAN FD transceiver that enhances the maximum data rate achievable in complex star topologies by minimizing signal ringing. Signal ringing is the result of reflections caused by impedance mismatch at various points in a CAN network due to the nodes that act as stubs.

An example of a complex network is shown in Figure 7-1.

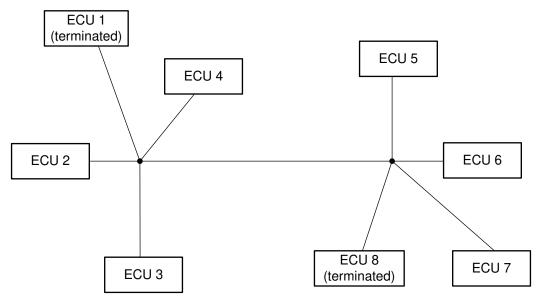
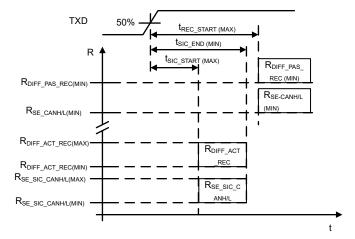


Figure 7-1. CAN Network: Star topology

Recessive-to-dominant signal edge is usually clean and driven by the transmitter. For a regular CAN FD transceiver, dominant-to-recessive edge is when the driver output impedance goes to approximately $60k\Omega$ and signal reflected back experiences impedance mismatch which causes ringing. TCAN1472-Q1 resolves this issue by TX-based Signal improvement capability (SIC). The device continues to drive the bus recessive until $t_{SIC_TX_base}$, so the reflections die down and the recessive bit is clean at sampling point. In the active recessive phase, transmitter output impedance is low (approximately 100Ω). After this phase is over and device goes to passive recessive phase, driver output impedance goes to high-Z. This phenomenon is explained with Figure 7-2.

For more information on the TI signal improvement technology and the compares with similar devices in market, please refer to the white paper *How Signal Improvement Capability Unlocks the Real Potential of CAN-FD Transceivers*.







7.2 Functional Block Diagram

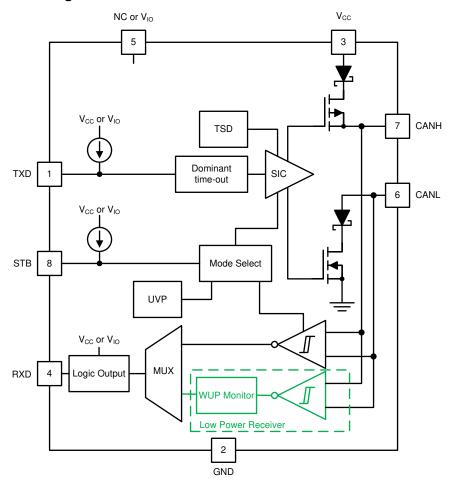


Figure 7-3. Block Diagram



7.3 Feature Description

7.3.1 Pin Description

7.3.1.1 TXD

The TXD input is a logic-level signal from a CAN controller to the transceiver. The input is referenced to V_{CC} for TCAN1472-Q1, or to V_{IO} for TCAN1472V-Q1.

7.3.1.2 GND

GND is the ground pin of the transceiver. The pin must be connected to the PCB ground.

7.3.1.3 V_{CC}

 V_{CC} provides the 5V power supply to the CAN transceiver.

7.3.1.4 RXD

The RXD output is a logic-level signal from the CAN transceiver to the CAN controller. The output is referenced to V_{CC} for TCAN1472-Q1 and V_{IO} for TCAN1472V-Q1. For TCAN1472V-Q1, RXD is only driven once V_{IO} is present.

When a wake event takes place, RXD is driven low.

7.3.1.5 V_{IO} (TCAN1472V-Q1 only)

The V_{IO} pin provides the digital I/O voltage to match the CAN controller voltage; thus, avoiding the requirement for a level shifter. The pin supports a wide range of controller interface voltage levels from 1.7V to 5.5V.

7.3.1.6 CANH and CANL

These are the CAN high and CAN low differential bus pins. The pins are connected to the CAN transceiver and the low-voltage WUP CAN receiver.

7.3.1.7 STB (Standby)

The STB pin is an input pin used for mode control of the transceiver. The STB pin can be supplied from either the system processor or from a static system voltage source. If normal mode is the only intended mode of operation, then the STB pin can be tied directly to GND.

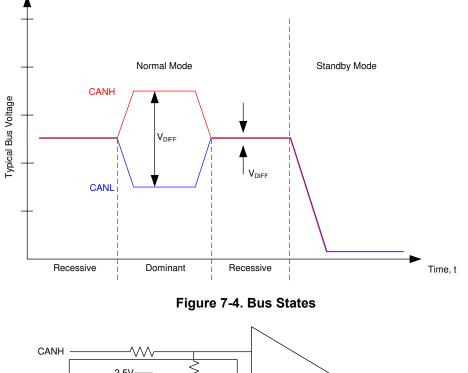
7.3.2 CAN Bus States

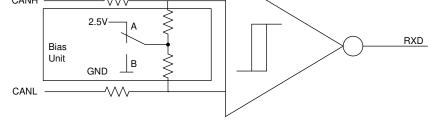
The CAN bus has two logical states during operation: recessive and dominant. See Figure 7-4 and Figure 7-5.

A dominant bus state occurs when the bus is driven differentially and corresponds to a logic low on the TXD and RXD pins. A recessive bus state occurs when the bus is biased to $V_{CC}/2$ via the high-resistance internal input resistors (R_{IN}) of the receiver and corresponds to a logic high on the TXD and RXD pins.

A dominant state overwrites the recessive state during arbitration. Multiple CAN nodes may be transmitting a dominant bit at the same time during arbitration, and in this case the differential voltage of the bus is greater than the differential voltage of a single driver.

The TCAN1472-Q1 transceiver implements a low-power standby (STB) mode which enables a third bus state where the bus pins are weakly biased to ground via the high resistance internal resistors of the receiver. See Figure 7-4 and Figure 7-5.





- A. Normal Mode
- B. Standby Mode

Figure 7-5. Simplified Recessive Common Mode Bias Unit and Receiver

7.3.3 TXD Dominant Timeout (DTO)

During normal mode, the only mode where the CAN driver is active, the TXD DTO circuit prevents the local node from blocking network communication in the event of a hardware or software failure where TXD is held dominant longer than the timeout period t_{TXD_DTO} . The TXD DTO circuit is triggered by a falling edge on TXD. If no rising edge is seen before the timeout period of the circuit, t_{TXD_DTO} , the CAN driver is disabled. Freeing the bus for communication between other nodes on the network. The CAN driver is reactivated when a recessive signal is seen on the TXD pin; thus, clearing the dominant time out. The receiver remains active and biased to $V_{CC}/2$ and the RXD output reflects the activity on the CAN bus during the TXD DTO fault.

The minimum dominant TXD time allowed by the TXD DTO circuit limits the minimum possible transmitted data rate of the device. The CAN protocol allows a maximum of eleven successive dominant bits (on TXD) for the worst case, where five successive dominant bits are followed immediately by an error frame. The minimum transmitted data rate may be calculated using Equation 1.

Minimum Data Rate = 11 bits / t_{TXD DTO} = 11 bits / 1.2ms = 9.2kbps

(1)



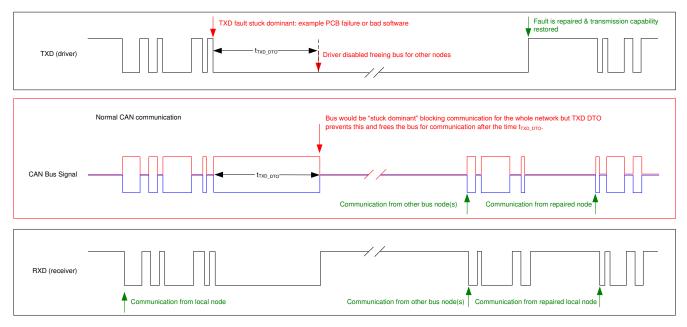


Figure 7-6. Example Timing Diagram for TXD Dominant Timeout

7.3.4 CAN Bus Short-circuit Current Limiting

The TCAN1472-Q1 has several protection features that limit the short-circuit current when a CAN bus line is shorted. These include CAN driver current limiting in the dominant and recessive states and TXD dominant state timeout which prevents permanently having the higher short-circuit current of a dominant state in case of a system fault. During CAN communication the bus switches between the dominant and recessive states; thus, the short-circuit current may be viewed as either the current during each bus state or as a DC average current. When selecting termination resistors or a common mode choke for the CAN design the average power rating, I_{OS(AVG)}, should be used. The percentage dominant is limited by the TXD DTO and the CAN protocol which has forced state changes and recessive bits due to bit stuffing, control fields, and inter frame space. These make sure there is a minimum amount of recessive time on the bus even if the data field contains a high percentage of dominant bits.

The average short-circuit current of the bus depends on the ratio of recessive to dominant bits and their respective short-circuit currents. The average short-circuit current may be calculated using Equation 2.

 $I_{OS(AVG)} = \% \text{ Transmit } x \left[(\% \text{ REC}_{Bits } x I_{OS(SS) REC}) + (\% \text{ DOM}_{Bits } x I_{OS(SS) DOM}) \right] + \left[\% \text{ Receive } x I_{OS(SS) REC} \right]$ (2)

Where:

- I_{OS(AVG)} is the average short-circuit current
- % Transmit is the percentage the node is transmitting CAN messages
- % Receive is the percentage the node is receiving CAN messages
- % REC_Bits is the percentage of recessive bits in the transmitted CAN messages
- % DOM_Bits is the percentage of dominant bits in the transmitted CAN messages
- I_{OS(SS) REC} is the recessive steady state short-circuit current
- I_{OS(SS)} DOM is the dominant steady state short-circuit current

This short-circuit current and the possible fault cases of the network are taken into consideration when sizing the power supply used to generate the transceivers V_{CC} supply.



7.3.5 Thermal Shutdown (TSD)

If the junction temperature of the TCAN1472-Q1 exceeds the thermal shutdown threshold, T_{TSD}, the device turns off the CAN driver circuitry and blocks the TXD to bus transmission path. The shutdown condition is cleared when the junction temperature of the device drops below T_{TSD} . The CAN bus pins are biased to $V_{CC}/2$ during a TSD fault and the receiver to RXD path remains operational. The TCAN1472-Q1 TSD circuit includes hysteresis which prevents the CAN driver output from oscillating during a TSD fault.

7.3.6 Undervoltage Lockout

The supply pins, V_{CC} and V_{IO}, have undervoltage detection that places the device into a protected state. This protects the bus during an undervoltage event on either supply pin.

Table 7-1. Undervoltage Lockout, TCAN1472-Q1						
V _{cc}	DEVICE STATE	BUS	RXD PIN			
> UV _{VCC}	Normal	Per TXD	Mirrors bus			
< UV _{VCC}	Protected	High impedance	High impedance			

	Table 7-2. Undervoltage Lockout, TCAN1472V-Q1					
V _{cc}	V _{IO}	DEVICE STATE	BUS	RXD PIN		
> UV _{VCC}	> UV _{VIO}	Normal	Per TXD	Mirrors bus		
	> 11//	STB = V _{IO} : standby mode		V _{IO} : Remote wake request ⁽¹⁾		
< UV _{VCC}	> UV _{VIO}	STB = GND: Protected	High impodence	Recessive		
> UV _{VCC}	< UV _{VIO}	Protected	High impedance	High impedance		
< UV _{VCC}	< UV _{VIO}	Protected		High impedance		

(1) See Remote Wake Request via Wake-Up Pattern (WUP) in Standby Mode

Once the undervoltage condition is cleared and t_{MODE} has expired, the TCAN1472-Q1 transitions to normal mode and the host controller can send and receive CAN traffic again.

7.3.7 Unpowered Device

The TCAN1472-Q1 is designed to be a passive or no load to the CAN bus if the device is unpowered. The bus pins were designed to have low leakage currents when the device is unpowered to not load the bus. This is critical if some nodes of the network are unpowered while the rest of the of network remains operational.

The logic pins also have low leakage currents when the device is unpowered to not load other circuits which may remain powered.

7.3.8 Floating pins

The TCAN1472-Q1 has internal pull-ups on critical pins which place the device into known states if the pin floats. This internal bias should not be relied upon by design though, especially in noisy environments, but instead should be considered a failsafe protection feature.

When a CAN controller supporting open-drain outputs is used, an adequate external pull-up resistor must be chosen. Making sures the TXD output of the CAN controller maintains acceptable bit time to the input of the CAN transceiver. See Table 7-3 for details on pin bias conditions.

Pin Pull-up or Pull-down		Comment					
TXD	Pull-up	Weakly biases TXD towards recessive to prevent bus blockage or TXD DTO triggering					
STB	Pull-up	Weakly biases STB towards low-power standby mode to prevent excessive system power					

Table 7-3, Pin Bias



7.4 Device Functional Modes

7.4.1 Operating Modes

The TCAN1472-Q1 has two main operating modes; normal mode and standby mode. Operating mode selection is made by applying a high or low level to the STB pin on the TCAN1472-Q1.

STB	Device Mode	Driver	Receiver	RXD Pin			
High	Low current standby mode with bus wake-up	Disabled	Low-power receiver and bus monitor enable	High (recessive) until valid WUP is received. See ⁽¹⁾			
Low	Normal Mode	Enabled	Enabled	Mirrors bus state			

Table 7-4. Operating Modes

(1) See Remote Wake Request via Wake-Up Pattern (WUP) in Standby Mode

7.4.2 Normal Mode

This is the normal operating mode of the TCAN1472-Q1. The CAN driver and receiver are fully operational and CAN communication is bi-directional. The driver is translating a digital input on the TXD input to a differential output on the CANH and CANL bus pins. The receiver is translating the differential signal from CANH and CANL to a digital output on the RXD output.

7.4.3 Standby Mode

This is the low-power mode of the TCAN1472-Q1. The CAN driver and main receiver are switched off and bi-directional CAN communication is not possible. The low-power receiver and bus monitor circuits are enabled to allow for RXD wake-up requests via the CAN bus. A wake-up request is output to RXD as shown in Figure 7-7. The local CAN protocol controller should monitor RXD for transitions (high-to-low) and reactivate the device to normal mode by pulling the STB pin low. The CAN bus pins are weakly pulled to GND in this mode (see Figure 7-4 and Figure 7-5).

In standby mode, only the V_{IO} supply is required therefore the V_{CC} may be switched off for additional system level current savings.

7.4.3.1 Remote Wake Request via Wake-Up Pattern (WUP) in Standby Mode

The TCAN1472-Q1 supports a remote wake-up request that is used to indicate to the host controller that the bus is active and the node should return to normal operation.

The device uses the multiple filtered dominant wake-up pattern (WUP) from the ISO 11898-2:2024 standard to qualify bus activity. Once a valid WUP has been received, the wake request is indicated to the controller by a falling edge and low period corresponding to a filtered dominant on the RXD output of the TCAN1472-Q1.

The Wake-Up Pattern (WUP) comprises four pulses: a filtered dominant, followed by a filtered recessive, then another filtered dominant, and finally another filtered recessive. After the first filtered dominant pulse, the bus monitor waits for a filtered recessive without being reset by other bus traffic and does the same until second filtered recessive pulse. Upon receiving the second filtered recessive pulse, WUP is recognized. RXD is set permanently low upon subsequent dominant pulses.

For a dominant or recessive to be considered filtered, the bus must be in that state for more than the t_{WK_FILTER} time. Due to variability in t_{WK_FILTER} the following scenarios are applicable. Bus state times less than $t_{WK_FILTER(MIN)}$ are never detected as part of a WUP, and therefore, no wake request is generated. Bus state times between $t_{WK_FILTER(MIN)}$ and $t_{WK_FILTER(MAX)}$ may be detected as part of a WUP and a wake-up request may be generated. Bus state times greater than $t_{WK_FILTER(MAX)}$ are always detected as part of a WUP, and thus a wake request is always generated. See Figure 7-7 for the timing diagram of the wake-up pattern.

The pattern and t_{WK_FILTER} time used for the WUP prevents noise and bus stuck dominant faults from causing false wake-up requests while allowing any valid message to initiate a wake-up request.

The ISO 11898-2:2024 standard has defined wakeup filter time to enable 1Mbps arbitration.

For an additional layer of robustness and to prevent false wake-ups, the device implements a wake-up timeout feature. For a remote wake-up event to successfully occur, the entire WUP must be received within the timeout



value t \leq t_{WK_TIMEOUT}. If not, the internal logic is reset and the transceiver remains in the current state without waking up. The full pattern must then be transmitted again, conforming to the constraints mentioned in this section. See Figure 7-7 for the timing diagram of the wake-up pattern with wake timeout feature.

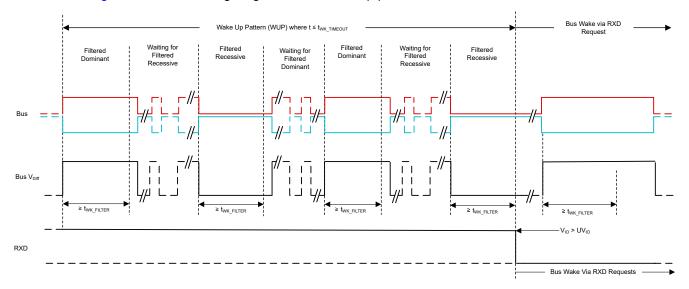


Figure 7-7. Wake-Up Pattern (WUP) with t_{WK_TIMEOUT}

7.4.4 Driver and Receiver Function

The digital logic input and output levels for the TCAN1472-Q1 are CMOS levels with respect to V_{CC} . For TCAN1472V-Q1, these are referred to V_{IO} for compatibility with MCUs having 1.8V, 2.5V, 3.3V, or 5V supply.

Table 7-5. Driver Function Table						
Device Mode	TXD Input ⁽¹⁾	Bus Outputs		Driven Bus State ⁽²⁾		
Device widde		CANH	CANL	Driven bus State		
Normal	Low	High	Low	Dominant		
Normai	High or open	High impedance	High impedance	Biased recessive		
Standby	y X High impedance High impedance Biased		Biased to ground			

(1) X = irrelevant

(2) For bus state and bias see Figure 7-4 and Figure 7-5.

Table 7-6. Receiver Function Table Normal and Standby Mode

Device Mode	CAN Differential Inputs V _{ID} = V _{CANH} – V _{CANL}	Bus State	RXD Pin
	V _{ID} ≥ 0.9V	Dominant	Low
Normal	0.5V < V _{ID} < 0.9V	Undefined	Undefined
	V _{ID} ≤ 0.5V	Recessive	High
	V _{ID} ≥ 1.15V	Dominant	High
Standby	0.4V < V _{ID} < 1.15V	Undefined	Low if a remote wake event occurred.
	V _{ID} ≤ 0.4V	Recessive	See Figure 7-7
Any	Open (V _{ID} ≈ 0V)	Open	High



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The TCAN1472-Q1 transceiver can be used in applications with a host controller or FPGA that includes the link layer portion of the CAN protocol. Figure 8-1 shows a typical configuration for 5V controller applications. The bus termination is shown for illustrative purposes.

8.2 Typical Application

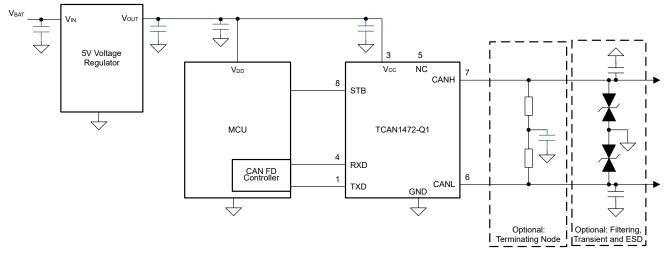


Figure 8-1. Transceiver Application Using 5V I/O Connections



8.2.1 Design Requirements

8.2.1.1 CAN Termination

Termination may be a single 120Ω resistor at each end of the bus, either on the cable or in a terminating node. If filtering and stabilization of the common-mode voltage of the bus is desired then split termination may be used, see Figure 8-2. Split termination improves the electromagnetic emissions behavior of the network by filtering higher-frequency common-mode noise that may be present on the differential signal lines.

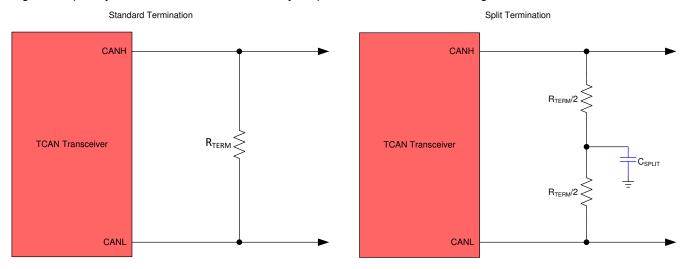


Figure 8-2. CAN Bus Termination Concepts

8.2.2 Detailed Design Procedures

8.2.2.1 Bus Loading, Length and Number of Nodes

A typical CAN application may have a maximum bus length of 40 meters and maximum stub length of 0.3 m. However, with careful design, users can have longer cables, longer stub lengths, and many more nodes to a bus. A high number of nodes requires a transceiver with high input impedance such as the TCAN1472-Q1. Additionally, since TCAN1472-Q1 has SIC, in a given network size, higher data rate can be achieved because signal ringing is attenuated.

Many CAN organizations and standards have scaled the use of CAN for applications outside the original ISO 11898-2 standard. There are system level trade off decisions for data rate, cable length, and parasitic loading of the bus. Examples of these CAN systems level specifications are ARINC 825, CANopen, DeviceNet, SAE J2284, SAE J1939, and NMEA 2000.

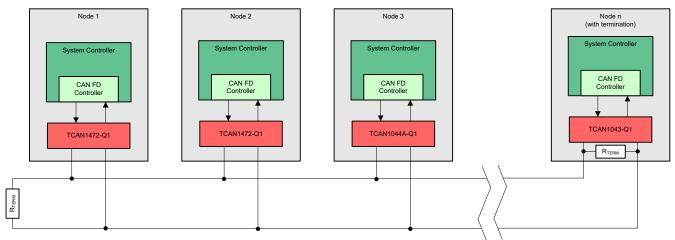
A CAN network system design is a series of tradeoffs. In the ISO 11898-2:2024 specification, the driver differential output is specified with a bus load that can range from 45Ω to 65Ω where the differential output must be greater than 1.5V. The TCAN1472-Q1 family is specified to meet the 1.5V requirement down to 45Ω bus load. The differential input resistance of the TCAN1472-Q1 is a minimum of $40k\Omega$. If 100 TCAN1472-Q1 transceivers are in parallel on a bus, this is equivalent to a 400Ω differential load in parallel with the nominal 60Ω bus termination which gives a total bus load of approximately 52Ω . Therefore, the TCAN1472-Q1 family theoretically supports over 100 transceivers on a single bus segment. However, for a CAN network design margin must be given for signal loss across the system and cabling, parasitic loadings, timing, network imbalances, ground offsets and signal integrity thus a practical maximum number of nodes is often lower. Bus length may also be extended beyond 40 meters by careful system design and data rate tradeoffs. For example, CANopen network design guidelines allow the network to be up to 1km with changes in the termination resistance, cabling, less than 64 nodes and significantly lowered data rate.

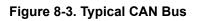
This flexibility in CAN network design is one of the key strengths of the various extensions and additional standards that have been built on the original ISO 11898-2 CAN standard. However, when using this flexibility the CAN network system, the designer must take the responsibility of good network design for a robust network operation.

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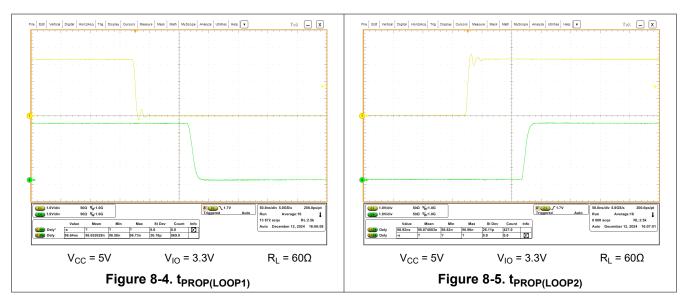
TCAN1472-Q1 SLLSFW8A – JUNE 2024 – REVISED DECEMBER 2024







8.2.3 Application Curves





8.3 System Examples

The TCAN1472-Q1 CAN transceiver is typically used in applications with a host controller or FPGA that includes the link layer portion of the CAN protocol. A 1.8V, 2.5V, or 3.3V application is shown in Figure 8-6. The bus termination is shown for illustrative purposes.

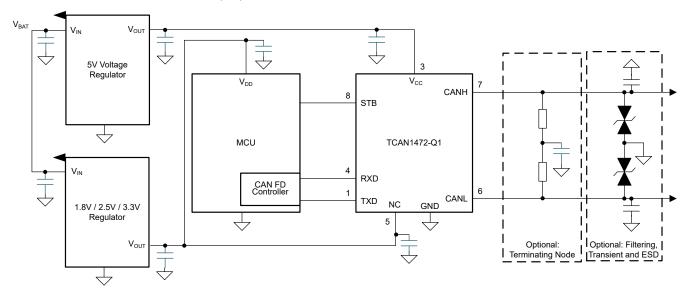


Figure 8-6. Typical Transceiver Application Using 1.8V, 2.5V, 3.3V IO Connections

8.4 Power Supply Recommendations

The TCAN1472-Q1 transceiver is designed to operate with a main V_{CC} input voltage supply range between 4.5V and 5.5V. The TCAN1472V-Q1 implements an I/O level shifting supply input, V_{IO}, designed for a range between 1.8V and 5.5V. Both supply inputs must be well regulated. A decoupling capacitance, typically 100nF, should be placed near the CAN transceiver main V_{CC} supply pin in addition to bypass capacitors. A decoupling capacitor, typically 100nF, should be placed near the CAN transceiver M_{IO} supply pin in addition to bypass capacitors.



8.5 Layout

8.5.1 Layout Guidelines

- Place the protection and filtering circuitry close to the bus connector, J1, to prevent transients, ESD, and noise from propagating onto the board. This layout example shows an optional transient voltage suppression (TVS) diode, D1, which may be implemented if the system-level requirements exceed the specified rating of the transceiver. This example also shows optional bus filter capacitors C4 and C5.
- Design the bus protection components in the direction of the signal path. Do not force the transient current to divert from the signal path to reach the protection device.
- Decoupling capacitors should be placed as close as possible to the supply pins V_{CC} and V_{IO} of transceiver.
- Use at least two vias for supply and ground connections of bypass capacitors and protection devices to minimize trace and via inductance.

Note

High frequency current follows the path of least impedance and not the path of least resistance.

This layout example shows how split termination could be implemented on the CAN node. The termination
is split into two resistors, R4 and R5, with the center or split tap of the termination connected to ground via
capacitor C3. Split termination provides common mode filtering for the bus. See CAN Termination, and CAN
Bus Short Circuit Current Limiting for information on termination concepts and power ratings needed for the
termination resistor(s).

8.5.2 Layout Example

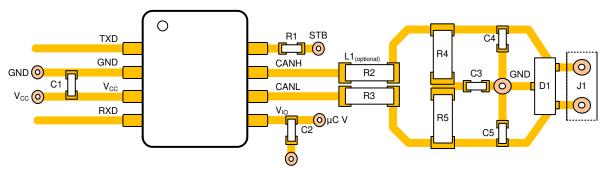


Figure 8-7. Layout Example



9 Device and Documentation Support

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

Changes from Revision * (June 2024) to Revision A (December 2024)					
•	Changed the document status from Advanced Information to Production data	1			

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins	-	Eco Plan	Lead finish/	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	Ball material	(3)		(4/5)	
							(6)				
PTCAN1472DDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	TBD	Call TI	Call TI	-40 to 150		Samples
PTCAN1472DRBRQ1	ACTIVE	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 150		Samples
PTCAN1472DRQ1	ACTIVE	SOIC	D	8	3000	TBD	Call TI	Call TI	-40 to 150		Samples
PTCAN1472VDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	TBD	Call TI	Call TI	-40 to 150		Samples
PTCAN1472VDRBRQ1	ACTIVE	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 150		Samples
PTCAN1472VDRQ1	ACTIVE	SOIC	D	8	3000	TBD	Call TI	Call TI	-40 to 150		Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



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GENERIC PACKAGE VIEW

VSON - 1 mm max height PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4203482/L

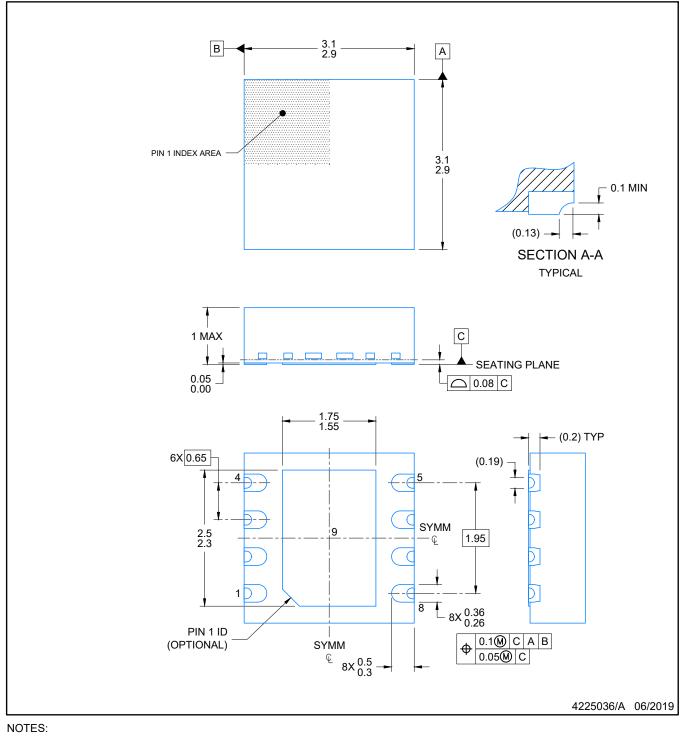


DRB0008J

PACKAGE OUTLINE

VSON - 1 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.

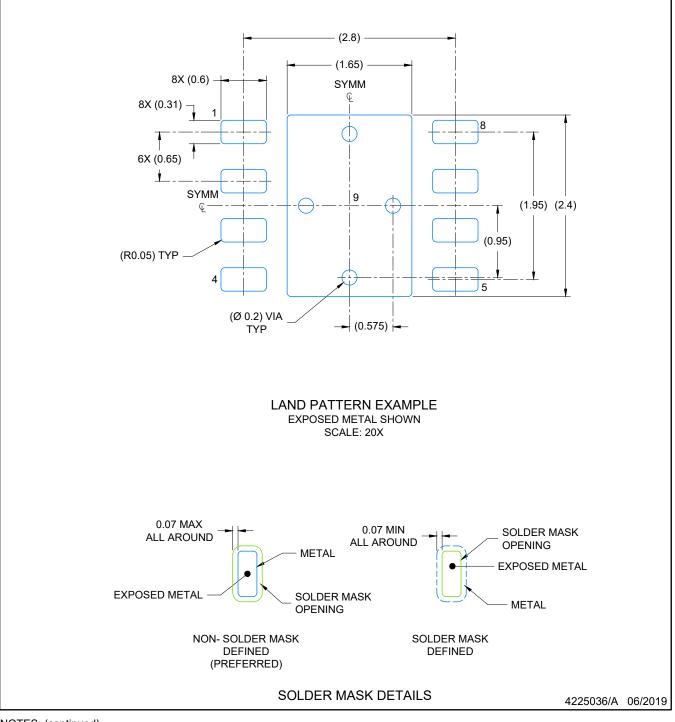


DRB0008J

EXAMPLE BOARD LAYOUT

VSON - 1 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

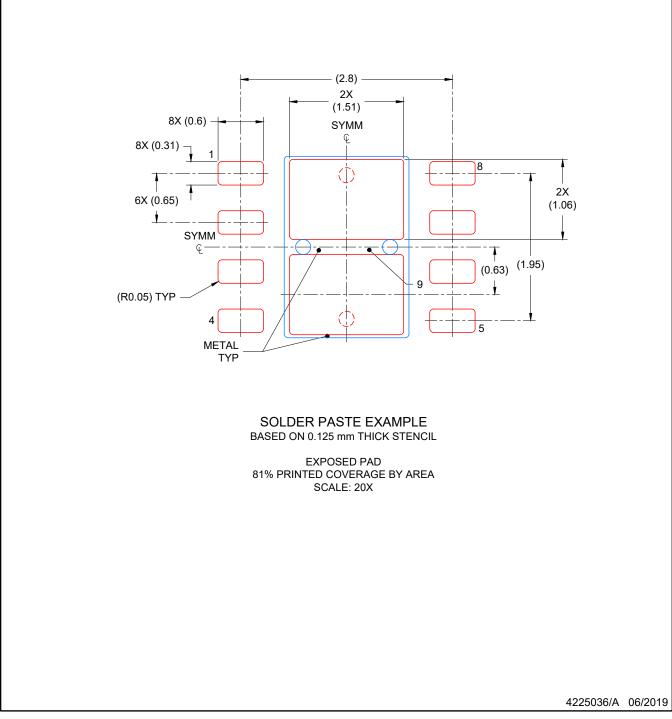


DRB0008J

EXAMPLE STENCIL DESIGN

VSON - 1 mm max height

PLASTIC QUAD FLAT PACK- NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



DDF0008A



PACKAGE OUTLINE

SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.



DDF0008A

EXAMPLE BOARD LAYOUT

SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



4. Publication IPC-7351 may have alternate designs.

5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DDF0008A

EXAMPLE STENCIL DESIGN

SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



^{6.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



^{7.} Board assembly site may have different recommendations for stencil design.

D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



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